

Features

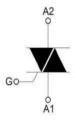
- Blocking voltage to 800V
- RMS on-state current to 4A
- General purpose switching



Package Marking and Ordering Information

Product ID	Pack	Packing Method	Qty(PCS)		
BT136-800E	TO-126	Bulk	200		





Maximum Ratings (Ta=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Value	Unit		
V _{DRM} /V _{RRM}	repetitive peak off-state voltage		800	V		
I _{T(RMS)}	RMS on-state current		4	Α		
1	Non repetitive surge peak	t = 2ms T _j = 25°C	40			
I _{TSM}	on-state current	t = 16.7ms T _j =25°C	35	Α		
l ² t	I ² t for fusing	t = 10 ms	2	A^2s		
dl/dt	Critical-rate of rise of I II III	I _G =2I _{GT} tr≤100ns	50	A/us		
	commutation current IV	F=120Hz	10	Ayus		
I _{GM}	Peak Gate Current	T _j =125°C tp=20µs	0.6	Α		
V_{GM}	Peak gate voltage	T _j =125 °C	1	V		
P _{GM}	Peak gate power	T _j =125 °C	1	W		
P _{G(AV)}	Average Gate Power Dissipation	T _j =125 °C	0.5	W		
Tj	Junction Temperature	-	-40 ~ 125	°C		
T _{stg}	Storage Temperature	-	-40 ~ 150	°C		

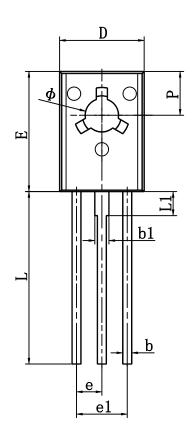


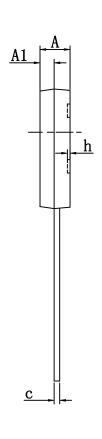
Electrical Characteristics (Ta=25°C unless otherwise specified)

Parameter		Symbol	Test conditions		Min	Тур	Max	Unit
Repetitive Peak Off-State Current Repetitive Peak Reverse Current		I _{DRM} ,I _{RRM}	V _{DRM} =V _{RRM} T _j =25 °C				5	μΑ
			$V_{DRM} = V_{RRM} T_j = 125 ^{\circ}C$				1	mA
Gate non-trigger voltage		V_{GD}	$V_D = 1/2V_{DRM}$		0.2			V
On-state voltage		V_{TM}	I _T =4A,t _p =380us				1.65	٧
	I	- I _{GT}	T ₂ (+), G(+)	V _D =12V R _L =100Ω			3	mA
Gate trigger current	II		T ₂ (+), G(-)				6	
Sate trigger current	III		T ₂ (-), G(-)				4	
	IV		T ₂ (-), G(+)				12	
	I	$V_{ ext{GT}}$	T ₂ (+), G(+)			0.8	2	- V
Gate trigger voltage	II		T ₂ (+), G(-)	V _D =12V		8.0	2	
Gate trigger voltage	III		T ₂ (-), G(-)	R _L =100Ω		8.0	2	
	IV		T ₂ (-), G(+)			8.0	2.5	
Holding current		lн	V _D =12V,I _{GT} =100mA				30	mA
Critical-rate of rise of commutation voltage		dV/dt	V_{DM} =67% V_{DRM} Gate open T_j =125 °C				50	V/us
Rate of change of commutating voltage		(dl/dt)c	V _{DM} =400V T _j =125 °C				20	V/us
			(dl/dt)c=5.4A/ms Gate open					
Turn-on time		t _{gt}	I _{TM} =16A ,V _{DM} =V _{DRM(MAX)} I _G =0.1A,dI _G dt=5A/uS				2	us



TO-126 Package Outline Dimensions





Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
Α	2.500	2.900	0.098	0.114	
A1	1.100	1.500	0.043	0.059	
b	0.660	0.860	0.026	0.034	
b1	1.170	1.370	0.046	0.054	
С	0.450	0.600	0.018	0.024	
D	7.400	7.800	0.291	0.307	
E	10.600	11.000	0.417	0.433	
е	2.290 TYP		0.090 TYP		
e1	4.480	4.680	0.176	0.184	
h	0.000	0.300	0.000	0.012	
L	15.300	15.700	0.602	0.618	
L1	2.100	2.300	0.083	0.091	
Р	3.900	4.100	0.154	0.161	
Ф	3.000	3.200	0.118	0.126	



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